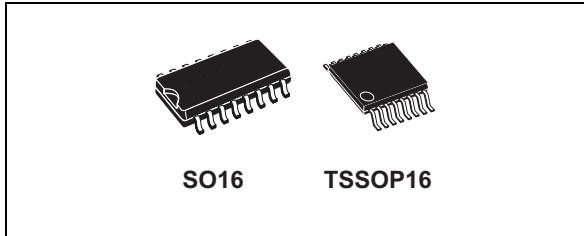


14-stage binary counter/oscillator

Datasheet - production data


Applications

- Automotive
- Industrial
- Computer
- Consumer

Description

The M74HC4060 device is a high speed CMOS 14-stage binary counter/oscillator fabricated with silicon gate C²MOS technology.

The oscillator configuration allows design of either RC or crystal oscillator circuits. A high level on the CLEAR accomplishes the reset function, i.e. all counter outputs are made low and the oscillator is disabled.

A negative transition on the clock input increments the counter. Ten kinds of divided output are provided; 4 to 10 and 12 to 14 stage inclusive. The maximum division available at Q12 is 1/16384 of the oscillator frequency.

The \bar{O} I input and the CLEAR input are equipped with protection circuits against static discharge and transient excess voltage.

Features

- High speed:
 $f_{\max} = 65 \text{ MHz (typ.) at } V_{CC} = 6 \text{ V}$
- Low power dissipation:
 $I_{CC} = 4 \text{ A (max.) at } T_A = 25 \text{ }^\circ\text{C}$
- High noise immunity:
 $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min.)}$
- Symmetrical output impedance:
 $|I_{OH}| = I_{OL} = 4 \text{ mA (min.)}$
- Balanced propagation delays: $T_{PLH} \cong T_{PHL}$
- Wide operating voltage range:
 $V_{CC} \text{ (opr.)} = 2 \text{ V to } 6 \text{ V}$
- Pin and function compatible with 74 series 4060
- ESD performance
 - HBM: 2 kV
 - MM: 200 V
 - CDM: 1 kV

Table 1. Device summary

Order code	Temperature range	Package	Packing	Marking
M74HC4060RM13TR	-55 °C to +125 °C	SO16	Tape and reel	74HC4060
M74HC4060YRM13TR ⁽¹⁾	-40 °C to +125 °C	SO16 (automotive version)		74HC4060Y
M74HC4060TTR	-55 °C to +125 °C	TSSOP16		HC4060
M74HC4060YTTR ⁽¹⁾	-40 °C to +125 °C	TSSOP16 (automotive version)		HC4060Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002.

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1 Pin description

Figure 1. Pin connection and IEC logic symbols

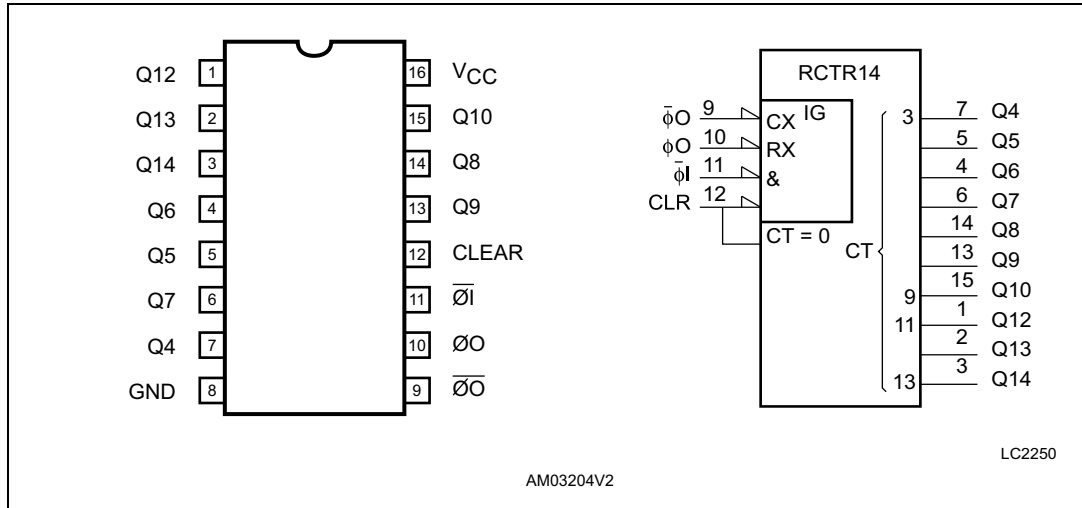


Table 2. Pin description

Pin no	Symbol	Name and function
1, 2, 3	Q12 to Q14	Counter outputs
7, 5, 4, 6, 14, 13, 15	Q4 to Q10	
9	ØØ	External capacitor connection
10	ØO	External resistor connection
11	ØI	Clock input / oscillator pin
12	CLEAR	Master reset
8	GND	Ground (0 V)
16	V _{CC}	Positive supply voltage

3 Electrical characteristics

Table 4. Absolute maximum ratings⁽¹⁾

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	-0.5 to +7	V
V_I	DC Input voltage	-0.5 to $V_{CC} + 0.5$	
V_O	DC output voltage		
I_{IK}	DC input diode current	20	mA
I_{OK}	DC output diode current		
I_O	DC output current	25	
I_{CC} or I_{GND}	DC VCC or ground current	50	
P_D	Power dissipation	500 ⁽²⁾	mW
T_{stg}	Storage temperature	-65 to +150	°C
T_L	Lead temperature (10 sec.)	300	

1. Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.
2. 500 mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C.

Table 5. Recommended operating conditions

Symbol	Parameter		Value	Unit
V_C	Supply voltage		2 to 6	V
V_I	Input voltage		0 to V_{CC}	
V_O	Output voltage			
T_{op}	Operating temperature		-55 to 125	°C
t_r, t_f	Input rise and fall time	$V_{CC} = 2.0\text{ V}$	0 to 1000	ns
		$V_{CC} = 4.5\text{ V}$	0 to 500	
		$V_{CC} = 6.0\text{ V}$	0 to 400	

Table 6. DC specifications

Symbol	Parameter	Test condition		Value						Unit	
		V _{CC} (V)		T _A = 25°C			-40 to 85 °C		-55 to 125 °C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V _{IH}	High level input voltage	2.0		1.5			1.5		1.5		V
		4.5		3.15			3.15		3.15		
		6.0		4.2			4.2		4.2		
V _{IL}	Low level input voltage	2.0				0.5		0.5		0.5	V
		4.5				1.35		1.35		1.35	
		6.0				1.8		1.8		1.8	
V _{OH}	High level output voltage (Q output)	2.0	I _O = -20 A	1.9	2.0		1.9		1.9		V
		4.5	I _O = -20 A	4.4	4.5		4.4		4.4		
		6.0	I _O = -20 A	5.9	6.0		5.9		5.9		
		4.5	I _O = -4.0 mA	4.18	4.31		4.13		4.10		
		6.0	I _O = -5.2 mA	5.68	5.8		5.63		5.60		
V _{OL}	Low level output voltage (Q output)	2.0	I _O = 20 A		0.0	0.1		0.1		0.1	V
		4.5	I _O = 20 A		0.0	0.1		0.1		0.1	
		6.0	I _O = 20 A		0.0	0.1		0.1		0.1	
		4.5	I _O = 4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I _O = 5.2 mA		0.18	0.26		0.33		0.40	
V _{OH}	High level output voltage (ØO, ØØ output)	2.0	I _O = -20 A	1.8	2.0		1.8		1.8	2.0	V
		4.5	I _O = -20 A	4.4	4.5		4.0		4.0		
		6.0	I _O = -20 A	5.5	5.9		5.5		5.5		
V _{OL}	Low level output voltage (ØO, ØØ output)	2.0	I _O = -20 A		0.0	0.2		0.2		0.2	V
		4.5	I _O = -20 A		0.0	0.5		0.5		0.5	
		6.0	I _O = -20 A		0.1	0.5		0.5		0.5	
I _I	Input leakage current	6.0	V _I = V _{CC} or GND			0.1		±1		±1	µA
I _{CC}	Quiescent supply current	6.0	V _I = V _{CC} or GND			4		40		80	µA

Table 7. AC electrical characteristics ($C_L = 50$ pF, input $t_r = t_f = 6$ ns)

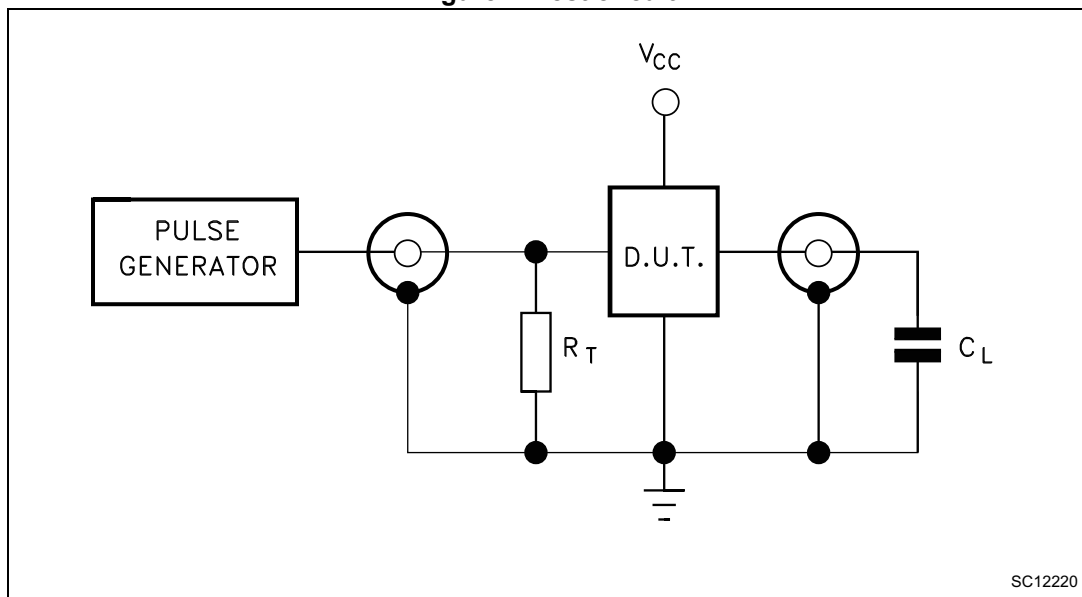
Symbol	Parameter	Test condition	Value						Unit		
			V_{CC} (V)	$T_A = 25$ °C			-40 to 85 °C			-55 to 125 °C	
				Min.	Typ.	Max.	Min.	Max.		Min.	Max.
t_{TLH} t_{THL}	Output transition time	2.0		30	75		95		110	ns	
		4.5		8	15		19		22		
		6.0		7	13		16		19		
t_{PLH} t_{PHL}	Propagation delay time ($\overline{Q1} - Q4$)	2.0		170	300		375		450	ns	
		4.5		41	60		75		90		
		6.0		30	51		64		76		
t_{PD}	Propagation delay time difference ($Q_n - Q_{n+1}$)	2.0		32	75		95		110	ns	
		4.5		7	15		19		22		
		6.0		5	13		16		19		
t_{PHL}	Propagation delay time (CLEAR - Q_n)	2.0		85	195		245		295	ns	
		4.5		23	39		49		59		
		6.0		17	33		42		50		
f_{MAX}	Maximum clock frequency	2.0	6	12		5		4		MHz	
		4.5	30	50		24		20			
		6.0	35	65		28		24			
$t_{W(H)}$, $t_{W(L)}$	Minimum pulse width ($\overline{Q1}$)	2.0		30	75		95		110	ns	
		4.5		8	15		19		22		
		6.0		7	13		16		19		
$t_{W(H)}$	Minimum pulse width (CLEAR)	2.0		30	75		95		110	ns	
		4.5		8	15		19		22		
		6.0		7	13		16		19		
t_{REM}	Minimum removal time	2.0		40	100		125		150	ns	
		4.5		10	20		25		30		
		6.0		9	17		21		26		

Table 8. Capacitive characteristics

Symbol	Parameter	Test condition	Value						Unit	
		V _{CC} (V)	T _A = 25 °C			-40 to 85 °C		-55 to 125 °C		
			Min.	Typ.	Max.	Min.	Max.	Min.		Max.
C _{IN}	Input capacitance	5.0	5	10		10		10		pF
C _{PD}	Power dissipation capacitance ⁽¹⁾	5.0		27						

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to [Figure 4: Test circuit](#)). Average operating current can be obtained by the following equation. $I_{CC(opr.)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$.

Figure 4. Test circuit



1. C_L = 50 pF or equivalent (includes jig and probe capacitance)
 R_T = Z_{OUT} of pulse generator (typically 50 Ω).

Figure 7. Waveform 3: propagation delay times (f = 1 MHz; 50 % duty cycle)

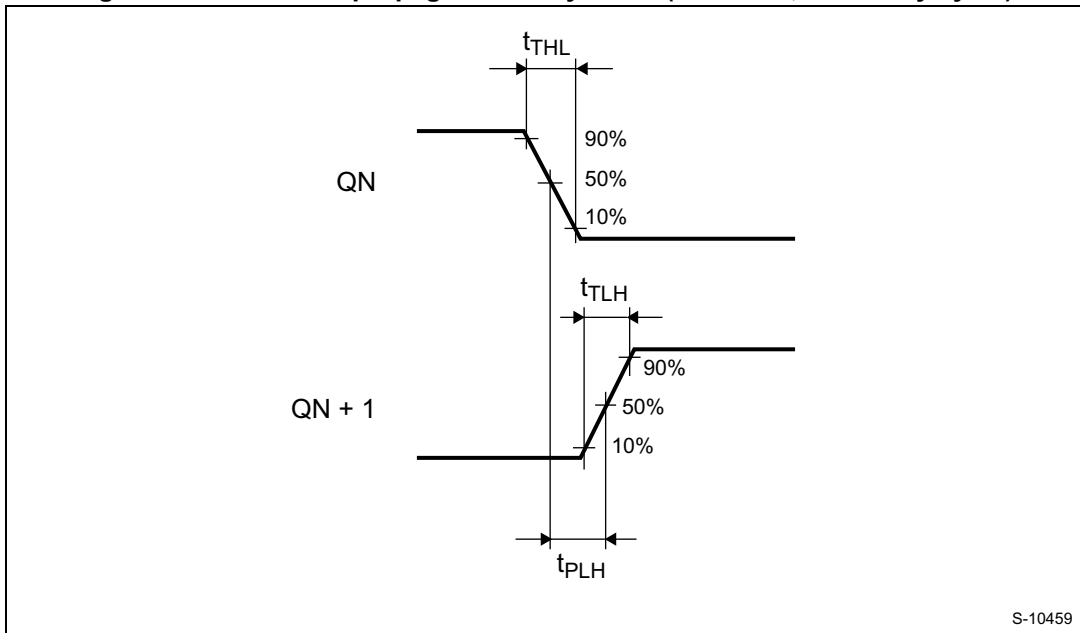


Figure 8. Waveform 4: propagation delay times (f = 1 MHz; 50 % duty cycle)

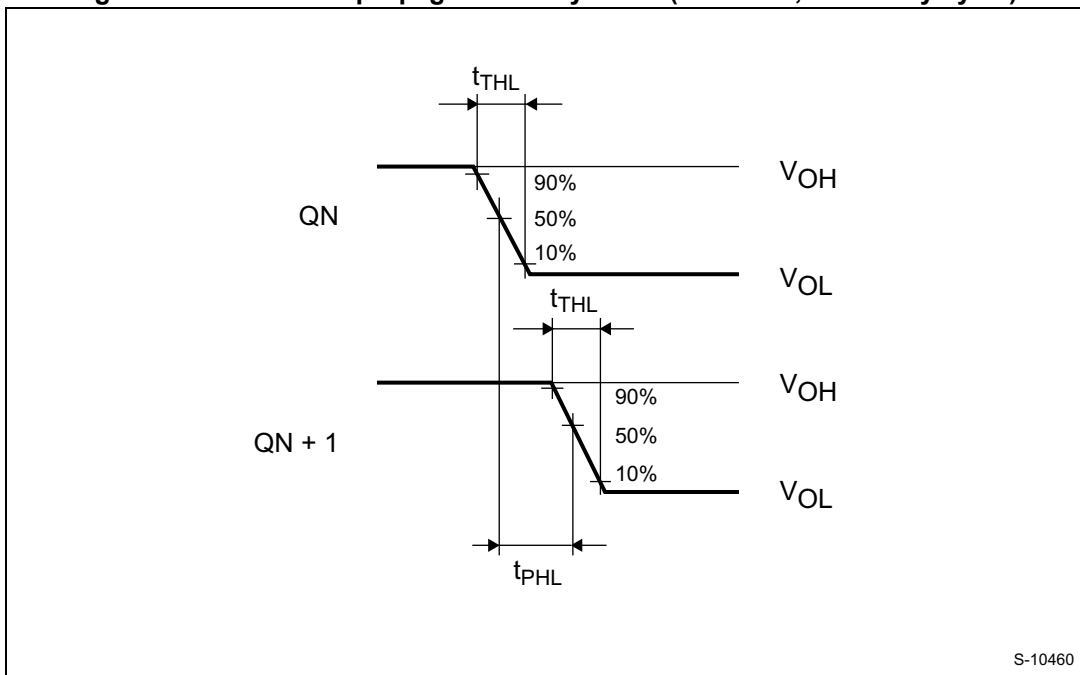
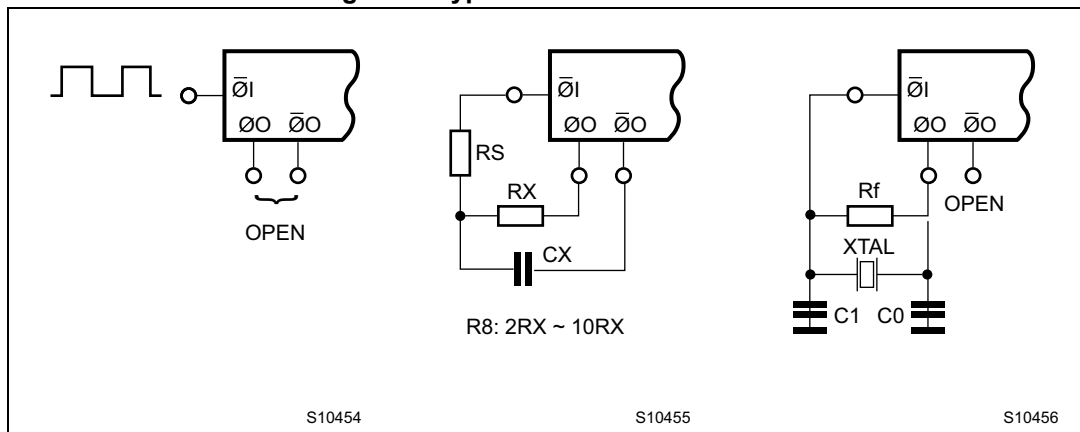


Figure 9. Typical clock drive circuits

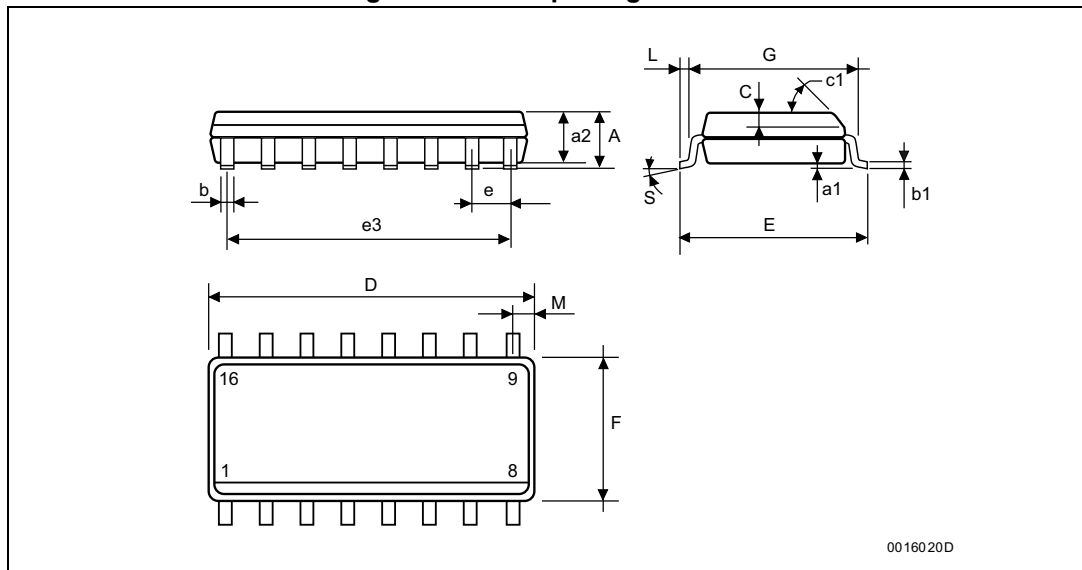


4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

4.1 SO16 package information

Figure 10. SO16 package outline



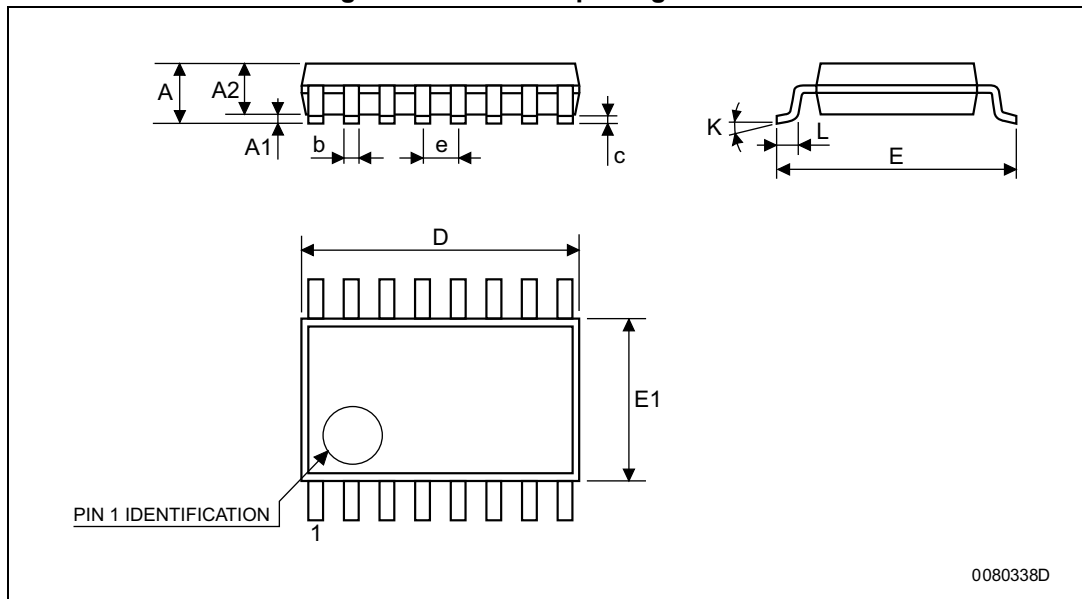
0016020D

Table 9. SO16 package mechanical data

Symbol	Dimensions					
	mm			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					

4.2 TSSOP16 package information

Figure 11. TSSOP16 package outline



0080338D

Table 10. TSSOP16 mechanical data

Symbol	Dimensions					
	mm			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65			0.0256	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

5 Ordering information

Table 11. Device summary

Order code	Temperature range	Package	Packing	Marking
M74HC4060RM13TR	-55 °C to +125 °C	SO16	Tape and reel	74HC4060
M74HC4060YRM13TR ⁽¹⁾	-40 °C to +125 °C	SO16 (automotive version)		74HC4060Y
M74HC4060TTR	-55 °C to +125 °C	TSSOP16		HC4060
M74HC4060YTTR ⁽¹⁾	-40 °C to +125 °C	TSSOP16 (automotive version)		HC4060Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002.

6 Revision history

Table 12. Document revision history

Date	Revision	Changes
1-Feb-2008	1	Initial release.
15-May-2013	2	<p>Added Applications on page 1.</p> <p>Corrected Description (replaced “The maximum division available at Q12 is 1/16384 f oscillator.” by “The maximum division available at Q12 is 1/16384 of the oscillator frequency.”).</p> <p>Updated Table 1 (added order codes, temperature range, updated package, added marking).</p> <p>Moved Figure 1 to page 3.</p> <p>Redrawn Figure 1, Figure 2, Figure 5 to Figure 9.</p> <p>Added Contents.</p> <p>Added titles to Section 1: Pin description to Section 6: Revision history.</p> <p>Added numbers to Table 1 to Table 12 and Figure 1 to Figure 11.</p> <p>Updated Section 4: Package information (added ECOPACK text, reversed order of Figure 10 to Figure 11 and Table 9 to Table 10).</p> <p>Minor corrections throughout document.</p>
10-Jan-2014	3	<p>Removed PDIP16 package</p> <p>Added ESD data to Features</p> <p>Table 1: Device summary: added “Packing” and updated footnote 1.</p> <p>Added Section 5: Ordering information</p> <p>Updated layout</p>

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

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